

**BYP53 / BYP54** 

25A SILICON POWER RECTIFIER DIODE

### Description

The BYP53/54 are plastic sealed 25A- diodes, which are available in different reverse voltage classes up to 800V.

The diodes can be delivered with limited forward voltage and reverse current differences for parallel connecting in rectifier stacks and back-off-diodes

### Applications

- Power supplies
- Rectifier diode in car generators

**Typical application circuit** 

- Rectifier bridges/stacks
- Back-off-diodes

- Features
- Forward current 25A

**Pinout details** 

- Reverse voltage 75V 800V
- Hermetic press-fit package
- Available in different modifications of the 
  package
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

# Image: Six pulse bridge connection Image: Six pu

### Ordering information

Device	Quantity per box	Options
BYP53-75;; BYP53-800		The package quantities for the different package
BYP54-75;; BYP54-800	100	modifications are included in "PressFitPackageModifications.pdf"

### **Device marking**

### Devices are identified by type. Colour of marking: BYP53- black, BYP54 - red

422	 date code 422 = 2004 week 22
/ ZETEX \	
BYP53	 diode type
400	 repetitive peak reverse voltage $V_{RRM}$ (in V) 400



## Absolute maximum ratings (at T<sub>amb</sub> = 25°C unless otherwise stated)

	Parameter	r	Symbol		Unit	Test condition			
	BYP53-75	BYP54-75		75	V				
	BYP53-100	BYP54-100		100					
	BYP53-150	BYP54-150		150					
	BYP53-200	BYP54-200		200					
Repetitive peak	BYP53-300	BYP54-300		300		T <sub>c</sub> = 140°C			
reverse voltage	BYP53-400	BYP54-400	Vrrm	400		1 <sub>c</sub> =140 C			
	BYP53-500	BYP54-500		500					
	BYP53-600	BYP54-600		600					
	BYP53-700	BYP54-700		700					
	BYP53-800	BYP54-800		800					
Forward cu	rrent, arithmetio	c value	IFAV	25	A				
Surge forward current		IFSM	425 350	A	half-sine wave, $\leq 10 \text{ ms}$ T <sub>J</sub> = 175°C half-sine wave, $\leq 10 \text{ ms}$				
Maximum rated value		∫i²dt	900 780	A²s	half-sine wave, $\leq 10 \text{ ms}$ T <sub>J</sub> = 175°C half-sine wave, $\leq 10 \text{ ms}$				
Repetitive peak forward current		I <sub>FRM</sub> =π*I <sub>FAV</sub>	79	A	f = >15 Hz				
Effective forward current		I <sub>FRMS</sub>	45	А					
Junction temperature		TJmax	175	°C					
Storage ter	nperature range		T <sub>stg</sub>	- 50 to + 140	°C				



### **Thermal resistance**

Parameter	Symbol	Value	Unit
Junction to case	Rejc	1.2	°C/W

### **Thermal characteristics**



# **Electrical characteristics** (at T<sub>amb</sub> = 25°C unless otherwise stated)





### Electrical characteristics (at T<sub>amb</sub> = 25°C unless otherwise stated)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions	
Forward voltage	BYP53-75800 BYP54-75800	VF	-	0.95	1.1	V	I <sub>F</sub> = 25 A, measuring time 10ms (half-sine wave)	
Forward voltage (information values)	BYP53-75800 BYP54-75800	VF	-	-	1.2	V	I <sub>F</sub> = 35 A,	
Reverse	BYP53-75150 BYP54-75150		-	-	3		TJ=140°C, at	
	BYP53-200800 BYP54-200800	IRRM	-	-	1.5	mA	VRRM	
current	BYP53-75400 BYP54-75400		-	-	0.25		at V <sub>RRM</sub>	
	BYP53-500800 BYP54-500800	IRRM	-	-	0.1	mA		
Threshold vo value)	Itage (information	V <sub>(FO)</sub>	-	0.66	-	V	TJ= 175°C	
Slope resista value)	nce (information	۲F	-	5.75		mΩ	TJ= 175°C	

# **Options: Electrical characteristics for parallel connecting** (at $T_{amb} = 25^{\circ}C$ unless otherwise stated)

Option	Parameter	Symbol	Min.	Тур.	Max.	Unit	Test contitions
1	Forward voltage difference in one category of forward voltage	ΔVF			0.05	V	I <sub>F</sub> = 25 A, measuring time 10ms (half-sine wave)
2	Reverse current in one category of forward voltage (only for BYP53-300800 and BYP54-300800)	IR		-	0.01	mA	at V <sub>RRM</sub>



## **Packaging details**



# Package dimensions

Dimensions in millimeters are control dimensions, dimensions in inches are approximate

DIM		Millimeters		Inches				
	MIN	ТҮР	MAX	MIN	TYP	MAX		
A	18,00	18,50	19,00	0,709	0,728	0,748		
A1	5,90	6,10	6,30	0,232	0,240	0,248		
A2	2,10	2,30	2,50	0,083	0,091	0,098		
D	15,50	15,70	15,90	0,610	0,618	0,626		
D1	12,72	12,77	12,82	0,501	0,503	0,505		
D2	11,50	11,70	11,90	0,453	0,461	0,469		
D3	1,33	1,36	1,39	0,052	0,054	0,055		



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